

Antibunched photons emitted by a quantum point contact out of equilibrium

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Motivated by the experimental search for “GHz nonclassical light”, we identify the conditions under which current fluctuations in a narrow constriction generate sub-Poissonian radiation. Antibunched electrons generically produce bunched photons, because the same photon mode can be populated by electrons decaying independently from a range of initial energies. Photon antibunching becomes possible at frequencies close to the applied voltage $V \times e/\hbar$, when the initial energy range of a decaying electron is restricted. The condition for photon antibunching in a narrow frequency interval below eV/\hbar reads $[\sum_n T_n(1 - T_n)]^2 < 2 \sum_n [T_n(1 - T_n)]^2$, with T_n an eigenvalue of the transmission matrix. This condition is satisfied in a quantum point contact, where only a single T_n differs from 0 or 1. The photon statistics is then a superposition of binomial distributions.

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In a recent experiment [1], Gabelli et al. have measured the deviation from Poisson statistics of photons emitted by a resistor in equilibrium at mK temperatures. By cross-correlating the power fluctuations they detected photon bunching, meaning that the variance $\text{Var } n = \langle n^2 \rangle - \langle n \rangle^2$ in the number of detected photons exceeds the mean photon count $\langle n \rangle$. Their experiment is a variation on the quantum optics experiment of Hanbury Brown and Twiss [2], but now at GHz frequencies.

In the discussion of the implications of their novel experimental technique, Gabelli et al. noticed that a general theory [3] for the radiation produced by a conductor out of equilibrium implies that the deviation from Poisson statistics can go either way: Super-Poissonian fluctuations ($\text{Var } n > \langle n \rangle$, signaling bunching) are the rule in conductors with a large number of scattering channels, while sub-Poissonian fluctuations ($\text{Var } n < \langle n \rangle$, signaling antibunching) become possible in few-channel conductors. They concluded that a quantum point contact could therefore produce GHz nonclassical light [4].

It is the purpose of this work to identify the conditions under which electronic shot noise in a quantum point contact can generate antibunched photons. The physical picture that emerges differs in one essential aspect from electron-hole recombination in a quantum dot or quantum well, which is a familiar source of sub-Poissonian radiation [5, 6, 7]. In those systems the radiation is produced by transitions between a few discrete levels. In a quantum point contact the transitions cover a continuous range of energies in the Fermi sea. As we will see, this continuous spectrum generically prevents antibunching, except at frequencies close to the applied voltage.

Before presenting a quantitative analysis, we first discuss the mechanism in physical terms. As depicted in Fig. 1, electrons are injected through a constriction in an energy range eV above the Fermi energy E_F , leaving behind holes at the same energy. The statistics of the charge Q transferred in a time $\tau \gg \hbar/eV$ is binomial [8], with $\text{Var } Q/e < \langle Q/e \rangle$. This electron antibunching is a result of the Pauli principle. Each scattering channel $n = 1, 2, \dots, N$ in the constriction and each energy inter-

val $\delta E = \hbar/\tau$ contributes independently to the charge statistics. The photons excited by the electrons would inherit the antibunching if there would be a one-to-one correspondence between the transfer of an electron and the population of a photon mode. Generically, this is not what happens: A photon of frequency ω can be excited by each scattering channel and by a range $eV - \hbar\omega$ of initial energies. The resulting statistics of photocounts is negative binomial [3], with $\text{Var } n > \langle n \rangle$. This is the same photon bunching as in black-body radiation [9].

In order to convert antibunched electrons into antibunched photons, it is sufficient to ensure a one-to-one correspondence between electron modes and photon modes. This can be realized by concentrating the current fluctuations in a single scattering channel and by restricting the energy range $eV - \hbar\omega$. Indeed, in a single-channel conductor and in a narrow frequency range $\omega \lesssim eV/\hbar$ we obtain sub-Poissonian photon statistics regardless of the value of the transmission probability. In the more general multi-channel case, photon antibunching is found if $[\sum_n T_n(1 - T_n)]^2 < 2 \sum_n [T_n(1 - T_n)]^2$ (with T_n an eigenvalue of the transmission matrix product tt^\dagger).

Starting point of our quantitative analysis is the general relationship of Ref. [3] between the photocount distribution $P(n)$ and the expectation value of an ordered exponential of the electrical current operator:

$$P(n) = \frac{1}{n!} \lim_{\xi \rightarrow -1} \frac{d^n}{d\xi^n} F(\xi), \quad (1)$$

$$F(\xi) = \left\langle \mathcal{O} \exp \left[\xi \int_0^\infty d\omega \gamma(\omega) I^\dagger(\omega) I(\omega) \right] \right\rangle. \quad (2)$$

We summarize the notation. The function $F(\xi) = \sum_{k=0}^\infty (\xi^k/k!) \langle n^k \rangle_f$ is the generating function of the factorial moments $\langle n^k \rangle_f \equiv \langle n(n-1)(n-2)\dots(n-k+1) \rangle$. The current operator $I = I_{\text{out}} - I_{\text{in}}$ is the difference of the outgoing current I_{out} (away from the constriction) and the incoming current I_{in} (toward the constriction). The symbol \mathcal{O} indicates ordering of the current operators from left to right in the order $I_{\text{in}}^\dagger, I_{\text{out}}^\dagger, I_{\text{out}}, I_{\text{in}}$. The real frequency-dependent response function $\gamma(\omega)$ is propor-

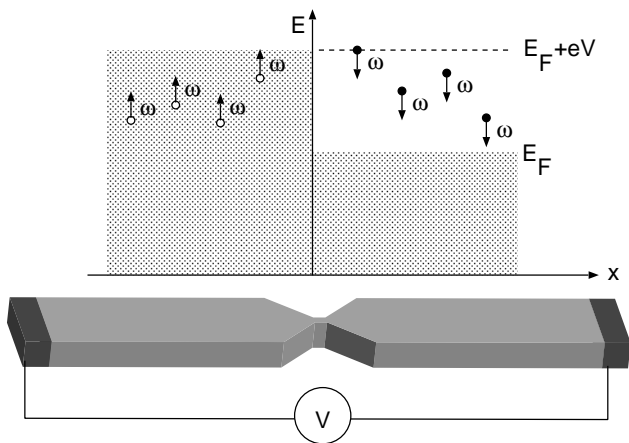


FIG. 1: Schematic diagram of a constriction in a conductor (bottom) and the energy range of electronic states (top), showing excitations of electrons (black dots) and holes (white dots) in the Fermi sea. A voltage V drops over the constriction. Electrons (holes) in an energy range $eV - \hbar\omega$ can populate a photon mode of frequency ω , by decaying to an empty (filled) state closer to the Fermi level.

tional to the coupling strength of conductor and photodetector and proportional to the detector efficiency. Positive (negative) ω corresponds to absorption (emission) of a photon by the detector. We consider photodetection by absorption, hence $\gamma(\omega) \equiv 0$ for $\omega \leq 0$. Integrals over frequency should be interpreted as sums over discrete modes $\omega_p = p \times 2\pi/\tau$, $p = 1, 2, 3, \dots$. The detection time τ is sent to infinity at the end of the calculation. We denote $\gamma_p = \gamma(\omega_p) \times 2\pi/\tau$, so that $\int d\omega \gamma(\omega) \rightarrow \sum_p \gamma_p$. For ease of notation we set $\hbar = 1$, $e = 1$.

The exponent in Eq. (2) is quadratic in the current operators, which complicates the calculation of the expectation value. We remove this complication by introducing a Gaussian field $z(\omega)$ and performing a Hubbard-Stratonovich transformation,

$$F(\xi) = \left\langle \mathcal{O} \exp \left[\sqrt{\xi} \int_0^\infty d\omega \gamma(\omega) [z(\omega) I^\dagger(\omega) + z^*(\omega) I(\omega)] \right] \right\rangle. \quad (3)$$

The brackets $\langle \dots \rangle$ now indicate both a quantum mechanical expectation value of the current operators and a classical average over independent complex Gaussian variables $z_p = z(\omega_p)$ with zero mean and variance $\langle |z_p|^2 \rangle = 1/\gamma_p$.

We assume zero temperature, so that the incoming current is noiseless. We may then replace I by I_{out} and restrict ourselves to energies ε in the range $(0, V)$ above E_F . Let $b_n^\dagger(\varepsilon)$ be the operator that creates an outgoing electron in scattering channel n at energy ε . The outgoing current is given in terms of the electron operators

by

$$I_{\text{out}}(\omega) = \int_0^V d\varepsilon \sum_n b_n^\dagger(\varepsilon) b_n(\varepsilon + \omega). \quad (4)$$

Energy $\varepsilon_p = p \times 2\pi/\tau$ is discretized in the same way as frequency. The energy and channel indices p, n are collected in a vector b with elements $b_{pn} = (2\pi/\tau)^{1/2} b_n(\varepsilon_p)$. Substitution of Eq. (4) into Eq. (3) gives

$$F(\xi) = \left\langle e^{b^\dagger Z b} e^{b^\dagger Z^\dagger b} \right\rangle. \quad (5)$$

The exponents contain the product of the vectors b, b^\dagger and a matrix Z with elements $Z_{pn, p'n'} = \xi^{1/2} \delta_{nn'} z_{p-p'} \gamma_{p-p'}$. Notice that Z is diagonal in the channel indices n, n' and lower-triangular in the energy indices p, p' .

Because of the ordering \mathcal{O} of the current operators, the single exponential of Eq. (3) factorizes into the two non-commuting exponentials of Eq. (5). In order to evaluate the expectation value efficiently, we would like to bring this back to a single exponential — but now with normal ordering \mathcal{N} of the fermion creation and annihilation operators. (Normal ordering means b^\dagger to the left of b , with a minus sign for each permutation.) This is accomplished by means of the operator identity [10]

$$\prod_i e^{b^\dagger A_i b} = \mathcal{N} \exp \left[b^\dagger \left(\prod_i e^{A_i} - 1 \right) b \right], \quad (6)$$

valid for any set of matrices A_i . The quantum mechanical expectation value of a normally ordered exponential is a determinant [11],

$$\langle \mathcal{N} e^{b^\dagger A b} \rangle = \text{Det} (1 + AB), \quad B_{ij} = \langle b_j^\dagger b_i \rangle. \quad (7)$$

In our case $A = e^Z e^{Z^\dagger} - 1$ and $B = tt^\dagger$, with t the $N \times N$ transmission matrix of the constriction.

In the experimentally relevant case [1, 12] the response function $\gamma(\omega)$ is sharply peaked at a frequency $\Omega \lesssim V$, with a width $\Delta \ll \Omega$. We assume that the energy dependence of the transmission matrix may be disregarded on the scale of Δ , so that we may choose an ε -independent basis in which tt^\dagger is diagonal. The diagonal elements are the transmission eigenvalues $T_1, T_2, \dots, T_N \in (0, 1)$. Combining Eqs. (5–7) we arrive at

$$F(\xi) = \left\langle \prod_{n=1}^N \text{Det} \left[1 + T_n (e^Z e^{Z^\dagger} - 1) \right] \right\rangle = \left\langle \prod_{n=1}^N \text{Det} \left[(1 - T_n) e^{-Z^\dagger} + T_n e^Z \right] \right\rangle. \quad (8)$$

(In the second equality we used that $\text{Det} e^{Z^\dagger} = 1$, since Z is a lower-triangular matrix.) The remaining average is over the Gaussian variables z_p contained in the matrix Z .

Since the interesting new physics occurs when Ω is close to V , we simplify the analysis by assuming that $\gamma(\omega) \equiv 0$ for $\omega < V/2$. For such a response function one has $Z^2 = 0$. (This amounts to the statement that no electron with excitation energy $\varepsilon < V$ can produce more than a single photon of frequency $\omega > V/2$.) We may therefore replace $e^Z \rightarrow 1+Z$ and $e^{-Z^\dagger} \rightarrow 1-Z^\dagger$ in Eq. (8). We then apply the matrix identity

$$\text{Det}(1+A+B) = \text{Det}(1-AB), \quad \text{if } A^2 = 0 = B^2, \quad (9)$$

and obtain

$$F(\xi) = \prod_p \frac{\gamma_p}{\pi} \int d^2 z_p e^{-\gamma_p |z_p|^2} \times \prod_{n=1}^N \text{Det}[1 + T_n(1 - T_n)\xi X]. \quad (10)$$

We have defined $\xi X \equiv ZZ^\dagger$ and written out the Gaussian average. The Hermitian matrix X has elements

$$X_{pp'} = \sum_q z_{p-q} z_{p'-q}^* \gamma_{p-q} \gamma_{p'-q}. \quad (11)$$

The integers p, p', q range from 1 to $V\tau/2\pi$.

The Gaussian average is easy if the dimensionless shot noise power $S = \sum_n T_n(1 - T_n)$ is $\gg 1$. We may then do the integrals of Eq. (10) in saddle-point approximation, with the result [13]

$$\ln F(\xi) = -\frac{\tau}{2\pi} \int_0^V d\omega \ln [1 - \xi S \gamma(\omega)(V - \omega)]. \quad (12)$$

The logarithm $\ln F(\xi)$ is the generating function of the factorial cumulants $\langle\langle n^k \rangle\rangle_f$ [14]. By expanding Eq. (12) in powers of ξ we find

$$\langle\langle n^k \rangle\rangle_f = (k-1)! \frac{\tau}{2\pi} \int_0^V d\omega [S \gamma(\omega)(V - \omega)]^k. \quad (13)$$

Eqs. (12) and (13) represent the multi-mode superposition of independent negative-binomial distributions [9]. All factorial cumulants are positive, in particular the second, so $\text{Var } n > \langle n \rangle$. This is super-Poissonian radiation.

When S is not $\gg 1$, e.g. when only a single channel contributes to the shot noise, the result (12-13) remains valid if $V - \Omega \gg \Delta$. This was the conclusion of Ref. [3], that narrow-band detection leads generically to a negative-binomial distribution. However, the saddle-point approximation breaks down when the detection frequency Ω approaches the applied voltage V . For $V - \Omega \lesssim \Delta$ one has to calculate the integrals in Eq. (10) exactly.

We have evaluated the generating function (10) for a response function of the block form

$$\gamma(\omega) = \begin{cases} \gamma_0 & \text{if } V - \Delta < \omega < V, \\ 0 & \text{if } \omega < V - \Delta, \end{cases} \quad (14)$$

with $\Delta < V/2$. The frequency dependence for $\omega > V$ is irrelevant. In the case $N = 1$ of a single channel, with transmission probability $T_1 \equiv T$, we find [15]

$$\begin{aligned} \ln F(\xi) &= \frac{\tau}{2\pi} \int_{V-\Delta}^V d\omega \ln [1 + \xi \gamma_0 T(1-T)(V - \omega)] \\ &= \frac{\tau \Delta (1+x) \ln(1+x) - x}{2\pi x}, \end{aligned} \quad (15)$$

with $x \equiv \xi \gamma_0 T(1-T)\Delta$. This is a superposition of binomial distributions. The factorial cumulants are

$$\langle\langle n^k \rangle\rangle_f = (-1)^{k+1} \frac{(k-1)!}{k+1} \frac{\tau \Delta}{2\pi} [T(1-T)\gamma_0 \Delta]^k. \quad (16)$$

The second factorial cumulant is negative, so $\text{Var } n < \langle n \rangle$. This is sub-Poissonian radiation.

We have not found such a simple closed-form expression in the more general multi-channel case, but it is straightforward to evaluate the low-order factorial cumulants from Eq. (10). We find

$$\langle n \rangle = \frac{\tau \Delta}{2\pi} \gamma_0 \Delta \frac{1}{2} S_1, \quad (17)$$

$$\langle\langle n^2 \rangle\rangle_f = \frac{\tau \Delta}{2\pi} (\gamma_0 \Delta)^2 \frac{1}{3} (S_1^2 - 2S_2), \quad (18)$$

$$\langle\langle n^3 \rangle\rangle_f = \frac{\tau \Delta}{2\pi} (\gamma_0 \Delta)^3 \frac{1}{6} (3S_1^3 - 15S_1 S_2 + 15S_3), \quad (19)$$

with $S_p = \sum_n [T_n(1 - T_n)]^p$. Antibunching therefore requires $S_1^2 < 2S_2$.

The condition on antibunching can be generalized to arbitrary frequency dependence of the response function $\gamma(\omega)$ in the range $V - \Delta < \omega < V$ of detected frequencies. For $\Delta < V/2$ we find

$$\begin{aligned} \text{Var } n - \langle n \rangle &= \frac{\tau}{2\pi} \int_{V-\Delta}^V d\omega' \gamma(\omega') \int_{\omega'}^V d\omega (V - \omega) \\ &\times \left(2S_1^2 - 4S_2 - (V - \omega) S_1^2 \frac{d}{d\omega} \right) \gamma(\omega). \end{aligned} \quad (20)$$

We see that the antibunching condition $S_1^2 < 2S_2$ derived for the special case of the block function (14) is more generally a sufficient condition for antibunching to occur, provided that $d\gamma/d\omega \geq 0$ in the detection range. It does not matter if the response function drops off at $\omega > V$, provided that it increases monotonically in the range $(V - \Delta, V)$. A steeply increasing response function in this range is more favorable, but not by much. For example, the power law $\gamma(\omega) \propto (\omega - V + \Delta)^p$ gives the antibunching condition $S_1^2 < 2S_2 \times [1 + p/(1+p)]$, which is only weakly dependent on the power p .

In conclusion, we have presented both a qualitative physical picture and a quantitative analysis for the conversion of electron to photon antibunching. A simple criterion, Eq. (18), is obtained for sub-Poissonian photon statistics, in terms of the transmission eigenvalues T_n of the conductor. Since an N -channel quantum point contact has only a single T_N different from 0 or 1, it

should generate antibunched photons in a frequency band $(V - \Delta, V)$ — regardless of the value of T_N . The statistics of these photons is the superposition (15) of binomial distributions, inherited from the electronic binomial distribution. There are no stringent conditions on the band width Δ , as long as it is $< V/2$ (in order to prevent multi-photon excitations by a single electron [16]). This should

make it feasible to use the cross-correlation technique of Ref. [1] to detect the emission of nonclassical microwaves by a quantum point contact.

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- [9] The *negative-binomial* distribution $P(n) \propto \binom{n+\nu-1}{n} [\nu/\langle n \rangle + 1]^{-n}$ counts the number of partitions of n bosons among $\nu = \tau\delta\omega/2\pi$ states in a frequency interval $\delta\omega$. The *binomial* distribution $P(n) \propto \binom{\nu}{n} [\nu/\langle n \rangle - 1]^{-n}$ counts the number of partitions of n fermions among ν states.
- [10] Eq. (6) is the multi-matrix generalization of the well known identity $\exp(b^\dagger A b) = \mathcal{N} \exp[b^\dagger (e^A - 1)b]$.
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- [13] The saddle point is at $z_p = 0$, so to integrate out the Gaussian fluctuations around the saddle point we may linearize the determinant in Eq. (10): $\prod_n \text{Det}[1 + T_n(1 - T_n)\xi X] = \exp[\xi S \text{Tr} X + \mathcal{O}(X^2)]$. The result is Eq. (12).
- [14] Factorial cumulants are constructed from factorial moments in the usual way. The first two are: $\langle\langle n \rangle\rangle_f = \langle n \rangle$, $\langle\langle n^2 \rangle\rangle_f = \langle n^2 \rangle_f - \langle n \rangle^2 = \text{Var } n - \langle n \rangle$.
- [15] Using computer algebra, we find that $\ln\langle \text{Det}[1 + \xi T(1 - T)X] \rangle = \sum_{m=1}^M \ln[1 + m\xi\gamma_0 T(1 - T)(2\pi/\tau)]$, for each matrix dimensionality M that we could check. We are confident that this closed form holds for all M , but we have not yet found an analytical proof. Eq. (15) follows in the limit $M \equiv \tau\Delta/2\pi \rightarrow \infty$ upon conversion of the summation into an integration.
- [16] Multi-photon excitations do not contribute to $\text{Var } n$ if $T_n \in \{0, 1/2, 1\}$ for all n [cf. Ref. [3], Eq. (19)]. For a quantum point contact, one finds that antibunching persists when $\Delta > V/2$ provided that $T_N(1 - T_N) > 1/6$.